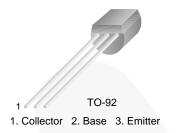
October 2014



# BC337 / BC338 NPN Epitaxial Silicon Transistor

## Features

- Switching and Amplifier Applications
- Suitable for AF-Driver Stages and Low-Power Output Stages
- Complement to BC327 / BC328



## **Ordering Information**

Part Number	Top Mark	Package	Packing Method	
BC33716BU	BC33716	TO-92 3L	Bulk	
BC33716TA	BC33716	TO-92 3L	Ammo	
BC33716TFR	BC33716	TO-92 3L	Tape and Reel	
BC33725BU	BC33725	TO-92 3L	Bulk	
BC33725TA	BC33725	TO-92 3L	Ammo	
BC33725TAR	BC33725	TO-92 3L	Ammo	
BC33725TF	BC33725	TO-92 3L	Tape and Reel	
BC33725TFR	BC33725	TO-92 3L	Tape and Reel	
BC33740BU	BC33740	TO-92 3L	Bulk	
BC33740TA	BC33740	TO-92 3L	Ammo	
BC33825TA	BC33825	TO-92 3L	Ammo	

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter		Value	Unit	
M	Collector Emitter Voltage	BC337	50	N	
V <sub>CES</sub>	Collector-Emitter Voltage	BC338	30	- v	
M	Collector-Emitter Voltage	BC337	45	V	
V <sub>CEO</sub>		BC338	25	v	
V <sub>EBO</sub>	Emitter-Base Voltage		5	V	
۱ <sub>C</sub>	Collector Current (DC)		800	mA	
Τ <sub>J</sub>	Junction Temperature		150	°C	
T <sub>STG</sub>	Storage Temperature		-55 to 150	°C	

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## Thermal Characteristics<sup>(1)</sup>

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Value	Unit
Power Dissipation		625	mW
PD	Derate Above 25°C	5.0	mW/°C
R <sub>θJA</sub>	Thermal Resistance, Junction-to-Ambient	200	°C/W

Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

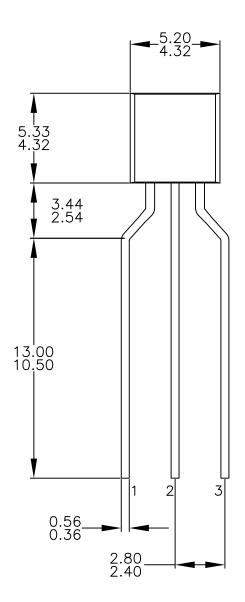
## **Electrical Characteristics**

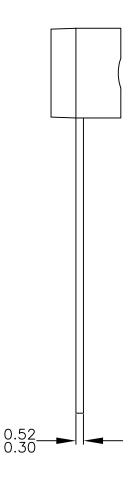
Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter		Conditions	Min.	Тур.	Max.	Unit
BV <sub>CEO</sub>	Collector-Emitter	BC337	$\frac{337}{I_{C}} = 10 \text{ mA}, I_{B} = 0$	45			V
DVCEO	Breakdown Voltage	BC338	$C = 10 \text{ mA}, I_{\text{B}} = 0$				v
BV <sub>CES</sub>	Collector-Emitter BC3			50			V
DVCES	Breakdown Voltage	BC338	I <sub>C</sub> = 0.1 mA, V <sub>BE</sub> = 0	30			V
$BV_{EBO}$	Emitter-Base Breakdown Voltage		$I_{E} = 0.1 \text{ mA}, I_{C} = 0$	5			V
1	I <sub>CES</sub> Collector Cut-Off Current	BC337	$V_{CE} = 45 \text{ V}, \text{ I}_{B} = 0$		2	100	nA
'CES		BC338	$V_{CE} = 25 \text{ V}, \text{ I}_{B} = 0$		2	100	ПА
h <sub>FE1</sub>	– DC Current Gain		$V_{CE} = 1 \text{ V}, I_{C} = 100 \text{ mA}$	100		630	
h <sub>FE2</sub>			$V_{CE} = 1 \text{ V}, I_{C} = 300 \text{ mA}$	60			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage		$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$			0.7	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage		$V_{CE} = 1 \text{ V}, \text{ I}_{C} = 300 \text{ mA}$			1.2	V
f <sub>T</sub>	Current Gain Bandwidth Product		$V_{CE}$ = 5 V, I <sub>C</sub> = 10 mA, f = 50 MHz		100		MHz
C <sub>ob</sub>	Output Capacitance		$V_{CB} = 10 \text{ V}, I_E = 0,$ f = 1 MHz		12		pF

## h<sub>FE</sub> Classification

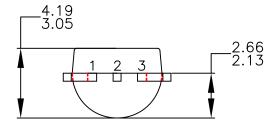
Classification	16	25	40
h <sub>FE1</sub>	100 ~ 250	160 ~ 400	250 ~ 630
h <sub>FE2</sub>	60 ~	100 ~	170 ~

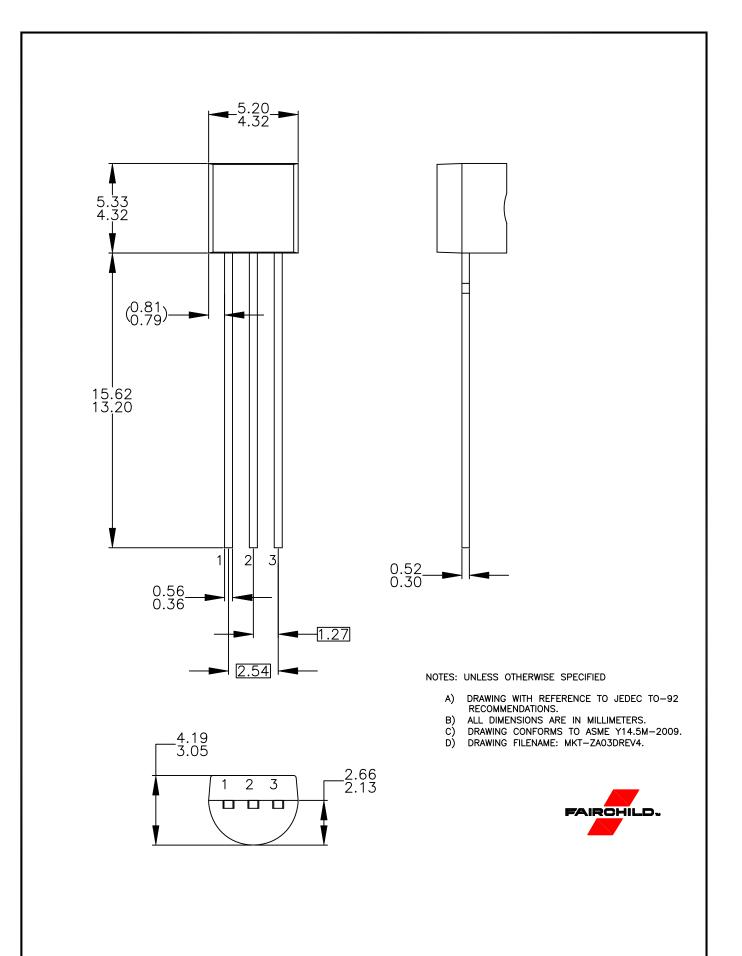


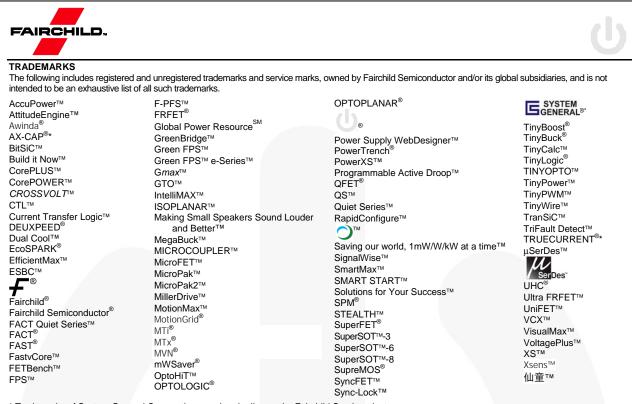


NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC. ALL DIMENSIONS ARE IN MILLIMETERS. DRAWING CONFORMS TO ASME Y14.5M-2009. DRAWING FILENAME: MKT-ZA03FREV3. FAIRCHILD SEMICONDUCTOR. Α.
- В. С. D. Е.







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